SN100KT5574 OCTAL ECL-TO-TTL TRANSLATOR WITH D-TYPE EDGE-TRIGGERED FLIP-FLOPS AND 3-STATE OUTPUTS

SDZS009 - D3418, JANUARY 1990

100K Compatible

- ECL Clock and TTL Control Inputs
- Flow-Through Architecture Optimizes PCB Layout
- Center Pin V_{CC}, V_{EE}, and GND Configurations Minimize High-Speed Switching Noise
- Package Options Include "Small Outline" Packages and Standard Plastic DIPs

description

This octal ECL-to-TTL translator is designed to provide efficient translation between a 100K ECL signal environment and a TTL signal environment.

24 🛮 1D 1Q[2Q[23 D 3Q∏ 3 22 T 3D 4Q**∏** 4 21 🕇 4D 20 TOE (TTL) V_{CC}[] 5 GND 6 19**∏** V_{EE} GND**∏** 7 18 GND 17 CLK(ECL) GND [8 5Q**∏** 9 16 T 5D 6Q**∏** 10 15 | 6D 14 7D 7Q[11 13**∏** 8D TD8 12

DW OR NT PACKAGE (TOP VIEW)

This device is designed specifically to improve the performance and density of ECL-to-TTL CPU/bus-oriented functions such as memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The eight flip-flops of the SN100KT5574 are edge-triggered D-type flip-flops. On the positive transition of the clock, the Q outputs are set to the logic levels that were set up at the D inputs.

A buffered output-enable input (\overline{OE}) can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance third state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

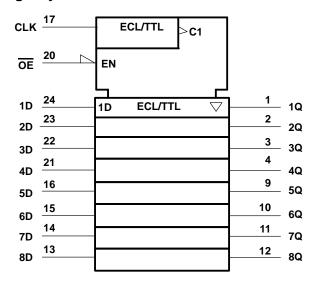
The output-enable input \overline{OE} does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are off.

The SN100KT5574 is characterized for operation from 0°C to 85°C.

FUNCTION TABLE

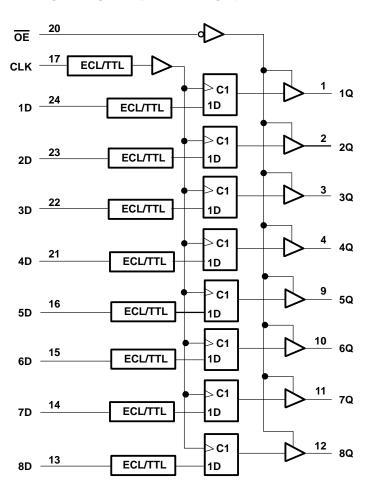
II	NPUTS	OUTPUT (TTL)	
OE	CLK	D	Q
L	1	Г	L
L	\uparrow	Н	Н
L	L	Χ	Qo
Н	Χ	Χ	Z

logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Supply voltage range, V _{EE}	8 V to 0 V
Input voltage range: TTL (see Note 1)	1.2 V to 7 V
ECL	V _{EE} to 0 V
Voltage applied to any output in the disabled or power-off state	0.5 V to 5.5 V
Voltage applied to any output in the high state	\dots -0.5 V to V _{CC}
Input current range, TTL	-30 mA to 5 mA
Current into any output in the low state	96 mA
Operating free-air temperature range	0°C to 85°C
Storage temperature range	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The TTL input voltage ratings may be exceeded provided the input current ratings are observed.

recommended operating conditions

		MIN	NOM	MAX	UNIT
VCC	TTL supply voltage	4.5	5	5.5	V
VEE	ECL supply voltage	-4.2	-4.5	-4.8	V
VIH	TTL high-level input voltage	2			V
VIL	TTL low-level input voltage			0.8	V
ΙK	TTL input clamp current			-18	mA
VIH	ECL high-level input voltage [‡]	-1150		-840	mV
V_{IL}	ECL low-level input voltage [‡]	-1810		-1490	mV
IOH	High-level output current			-15	mA
lOL	Low-level output current			48	mA
TA	Operating temperature range	0		85	°C

[‡] The algebraic convention, in which the least positive (most negative) value is designated minimum, is used in this data sheet for logic levels only.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP [†]	MAX	UNIT
VIK	OE only	$V_{CC} = 4.5 \text{ V},$	$V_{EE} = -4.2 \text{ V},$	I _I = -18 mA			-1.2	V
Voн		$V_{CC} = 4.5 \text{ V},$	$V_{EE} = -4.5 \text{ V} \pm 0.3 \text{ V},$	IOH = -3 mA	2.4	3.3		V
		$V_{CC} = 4.5 \text{ V},$	$V_{EE} = -4.5 \text{ V} \pm 0.3 \text{ V},$	$I_{OH} = -15 \text{ mA}$	2	3.1		
VOL		$V_{CC} = 4.5 \text{ V},$	$V_{EE} = -4.5 \text{ V} \pm 0.3 \text{ V},$	I _{OL} = 48 mA		0.38	0.55	V
Ц	OE only	$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	V _I = 7 V			0.1	mA
lн	OE only	$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	V _I = 2.7 V			20	μΑ
IJL	OE only	$V_{CC} = 5.5 \text{ V},$	VEE = -4.8 V,	V _I = 0.5 V			-0.5	mA
lн	Data inputs and CLK	$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	$V_{IH} = -840 \text{ mV}$			350	μΑ
Ι _Ι Γ	Data inputs and CLK	$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	V _{IL} = -1810 mV	0.50			μΑ
lozh		$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	V _O = 2.7 V			50	μΑ
lozL		$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	V _O = 0.5 V			-50	μΑ
los [‡]		$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.8 \text{ V},$	VO = 0 V	-100		-225	mA
ІССН		$V_{CC} = 5.5 \text{ V},$	VEE = -4.8 V			66	95	mA
ICCL		$V_{CC} = 5.5 \text{ V},$	VEE = -4.8 V			76	110	mA
ICCZ		$V_{CC} = 5.5 \text{ V},$	V _{EE} = -4.8 V			74	106	mA
IEE		$V_{CC} = 5.5 \text{ V},$	VEE = -4.8 V			-43	-61	mA
Ci		$V_{CC} = 5.5 \text{ V},$	V _{EE} = -4.5 V			5		pF
Co		$V_{CC} = 5.5 \text{ V},$	$V_{EE} = -4.5 \text{ V}$			7		pF

timing requirements

				$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$ $V_{EE} = -4.2 \text{ V to } -4.8 \text{ V},$ $T_A = \text{MIN to MAX}$		UNIT
				MIN	MAX	
t _W	Pulse duration	CLK high		4		
١W		CLK low		4		ns
	Hold time after CLK↑	Data high		1		
^t h		Data low		1		ns
t _{su}	Setup time before CLK↑	Data high		1		no
-su		Data low	•	1		ns

[§] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

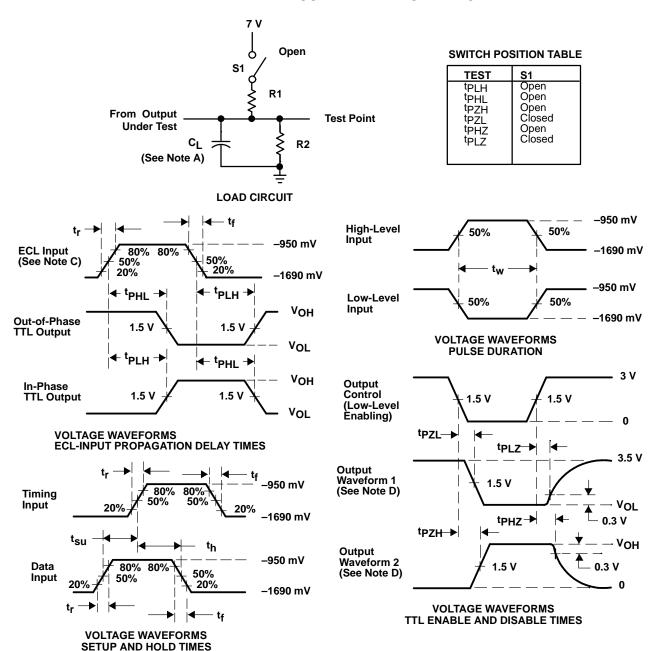
[†] All typical values are at V_{CC} = 5 V, V_{EE} = -4.5 V, T_A = 25°C. ‡ Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended ranges of operating free-air temperature and supply voltage (see Figure 1)

PARAMETER	FROM (INPUT)	TO R1 = 5			C_L = 50 pF, R1 = 500 Ω , R2 = 500 Ω	
			MIN	TYP [†]	MAX	
f _{max}			200	300		MHz
^t PLH	CLK	Q	2.3	4.1	7	ns
^t PHL		3	2.9	4.6	7.4	115
^t PZH	ŌĒ	Q	1.9	3.6	6.3	
^t PZL		3	2.7	4.8	7.7	ns
^t PHZ	ŌĒ	Q	2.1	3.9	6.1	ns
t _{PLZ}	OL	3	0.5	3.4	6.3	115

[†] All typical values are at $V_{CC} = 5$ V, $V_{EE} = -4.5$ V, $T_A = 25$ °C.

PARAMETER MEASUREMENT INFORMATION



- B. For TTL inputs, input pulses are supplied by generators having the following characteristics PRR \leq 10 MHz, $Z_0 = 50~\Omega$, $t_\Gamma \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- C. For ECL inputs, input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50~\Omega$, $t_\Gamma \leq 0.7~ns$, $t_f \leq 0.7~ns$.
- D. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- E. The outputs are measured one at a time with one transition per measurement.

figure 1. load circuit and voltage waveforms



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